SWITCHMODE Power Rectifiers

DPAK-3 Surface Mount Package

These state-of-the-art devices are designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Extremely Fast Switching
- Extremely Low Forward Drop
- Platinum Barrier with Avalanche Guardrings
- NRVBD Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 0.4 Gram (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Ratings:
 - ♦ Machine Model = C
 - ♦ Human Body Model = 3B



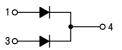
ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIERS 6.0 AMPERES, 20 – 60 VOLTS



DPAK CASE 369C



MARKING DIAGRAM



Y = Year
WW = Work Week
B6x0T = Device Code
x = 2, 3, 4, 5, or 6
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

		MBRD/NRVBD/SBR					
Rating	Symbol	620CT	630CT	640CT	650CT	660CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	30	40	50	60	V
Average Rectified Forward Current $T_C = 130^{\circ}C$ (Rated V_R) Per Diode Per Device	I _{F(AV)}	3 6				Α	
Peak Repetitive Forward Current, T _C = 130°C (Rated V _R , Square Wave, 20 kHz) Per Diode	I _{FRM}	6				Α	
Nonrepetitive Peak Surge Current – (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	75		Α			
Peak Repetitive Reverse Surge Current (2 μs, 1 kHz)	I _{RRM}	1			Α		
Operating Junction Temperature (Note 1)	TJ	-65 to +175		°C			
Storage Temperature	T _{stg}	-65 to +175			°C		
Voltage Rate of Change (Rated V _R)	dv/dt	10,000		V/μs			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS PER DIODE

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	6	°C/W
Maximum Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	80	°C/W

^{2.} Rating applies when surface mounted on the minimum pad size recommended.

ELECTRICAL CHARACTERISTICS PER DIODE

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 3) $ \begin{aligned} i_F &= 3 \text{ Amps, } T_C = 25^{\circ}\text{C} \\ i_F &= 3 \text{ Amps, } T_C = 125^{\circ}\text{C} \\ i_F &= 6 \text{ Amps, } T_C = 25^{\circ}\text{C} \\ i_F &= 6 \text{ Amps, } T_C = 125^{\circ}\text{C} \end{aligned} $	V _F	0.7 0.65 0.9 0.85	V
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, T _C = 25°C) (Rated dc Voltage, T _C = 125°C)	İR	0.1 15	mA

^{3.} Pulse Test: Pulse Width = 300 µs, Duty Cycle ≤ 2.0%.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

TYPICAL CHARACTERISTICS

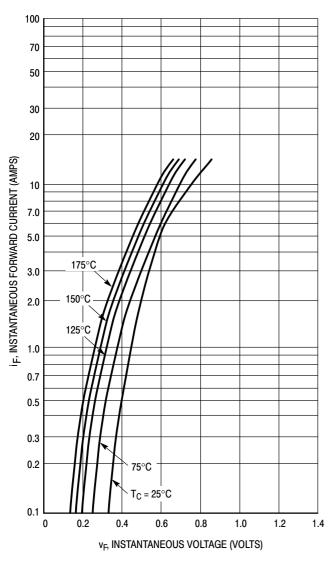
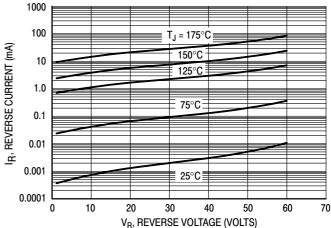


Figure 1. Typical Forward Voltage, Per Leg



*The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these curves if V_R is sufficient below rated V_R .

Figure 2. Typical Reverse Current,* Per Leg

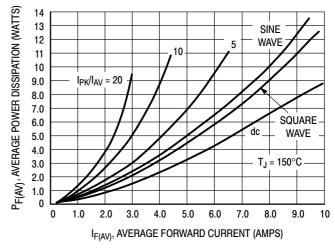


Figure 3. Average Power Dissipation, Per Leg

TYPICAL CHARACTERISTICS

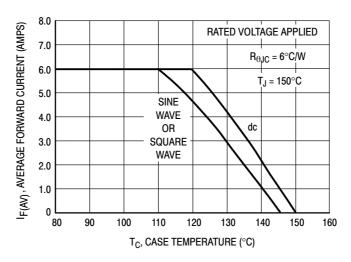


Figure 4. Current Derating, Case, Per Leg

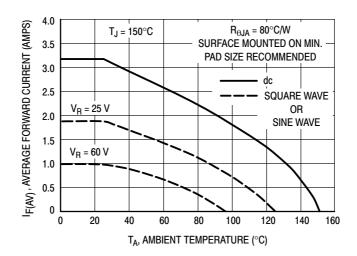


Figure 5. Current Derating, Ambient, Per Leg

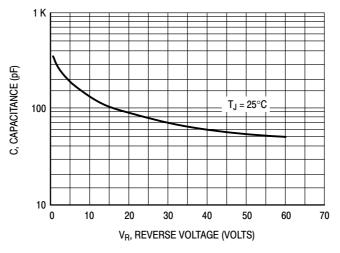


Figure 6. Typical Capacitance, Per Leg

ORDERING INFORMATION

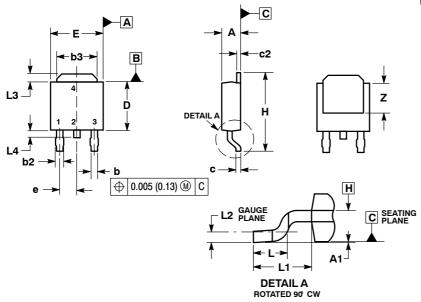
Device	Package	Shipping [†]
MBRD620CTT4G		2500 / Tape & Reel
MBRD630CTT4G		2500 / Tape & Reel
MBRD640CTG		75 Units / Rail
NRVBD640CTG		75 Units / Rail
MBRD640CTT4G		2500 / Tape & Reel
NRVBD640CTT4G		2500 / Tape & Reel
MBRD650CTG	DPAK	75 Units / Rail
MBRD650CTT4G	(Pb-Free)	2500 / Tape & Reel
NRVBD650CTT4G		2500 / Tape & Reel
MBRD660CTG		75 Units / Rail
NRVBD660CTG		75 Units / Rail
MBRD660CTRLG		1800 / Tape & Reel
MBRD660CTT4G		2500 / Tape & Reel
NRVBD660CTT4G	7	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE)

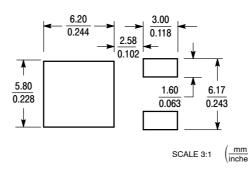
CASE 369C ISSUE D



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994
- 2. CONTROLLING DIMENSION: INCHES.
 3. THERMAL PAD CONTOUR OPTIONAL WITHIN DI-
- MENSIONS b3, L3 and Z.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
 5. DIMENSIONS D AND E ARE DETERMINED AT THE
- OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Ε	0.250	0.265	6.35	6.73	
е	0.090 BSC		2.29 BSC		
Н	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74 REF		
L2	0.020 BSC		0.51 BSC		
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0.155		3.93		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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